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DS280BR820

SNLS544B-SEPTEMBER 2016-REVISED OCTOBER 2019

DS280BR820 Low Power 28 Gbps 8 Channel Linear Repeater

Features 1

- Octal-Channel Multi-Protocol Linear Equalizer Supporting up to 28 Gbps Interfaces
- Low Power Consumption: 93 mW / Channel (Typical)
- No Heat Sink Required
- Linear Equalization for Seamless Support of Link Training, Auto-Negotiation, and FEC Pass-Through
- Extends Channel Reach by 17 dB+ Beyond Normal ASIC-to-ASIC Capability
- Ultra-Low Latency: 100 ps (Typical)
- Low Additive Random Jitter
- Small 8-mm x 13-mm BGA Package with Integrated RX AC Coupling Capacitors for Easy Flow-Through Routing
- Unique Pinout Allows Routing High-Speed Signals Underneath the Package
- **Pin-Compatible Retimer Available**
- Single 2.5-V ±5% Power Supply
- -40°C to +85°C Operating Temperature Range

2 Applications

- Backplane and Mid-Plane Reach Extension
- Front-Port Eye Opener for Optical and Passive Copper (100G-SR4/LR4/CR4)
- QSFP28, SFP28, CFP2, CFP4, CDFP

3 Description

The DS280BR820 is an extremely low-power, highperformance eight-channel linear equalizer supporting multi-rate, multi-protocol interfaces up to 28 Gbps. It is used to extend the reach and improve the robustness of high-speed serial links for backplane, front-port, and chip-to-chip applications.

The linear nature of the DS280BR820's equalization preserves the transmit signal characteristics, thereby allowing the host and link partner ASICs to freely negotiate transmit equalizer coefficients (100G-CR4/KR4). This transparency to the link training protocol facilitates system-level interoperability with minimal effect on the latency. Each channel operates independently, which allows the DS280BR820 to support individual lane Forward Error Correction (FEC) pass-through.

The DS280BR820's small package dimensions. optimized high-speed signal escape, and the pincompatible Retimer portfolio make the DS280BR820 ideal for high-density backplane applications. Simplified equalization control, low power consumption, and ultra-low additive jitter make it suitable for front-port interfaces such as 100G-SR4/LR4/CR4. The small 8-mm x 13-mm footprint easily fits behind numerous standard front-port connectors like QSFP, SFP, CFP2, CFP4, and CDFP without the need for a heat sink.

Integrated AC coupling capacitors (RX side) eliminate the need for external capacitors on the PCB. The DS280BR820 has a single power supply and minimal need for external components. These features reduce PCB routing complexity and bill of materials (BOM) cost.

A pin-compatible Retimer device is available for longer reach applications.

The DS280BR820 can be configured either through the SMBus or through an external EEPROM. Up to 16 devices can share a single EEPROM.

| Device | Information | (1 |
|--------|-------------|----|
|--------|-------------|----|

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|-------------|-------------|------------------|
| DS280BR820 | nFBGA (135) | 8.0 mm x 13.0 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimore PROPLICTION DATA

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NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| CI | hanges from Revision A (October 2017) to Revision B | Page |
|----|---|------|
| • | Initial Public Release | |

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5 Pin Configuration and Functions

| | | | | | | | | | | Тор | o View | | | | | |
|---|---------------------|-----------|-------------------|-----|------|-----|------|-----|------|-----|--------|-----|--------------------|-----------|--------------------|---|
| | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | |
| J | GND | GND | TX1N | GND | TX2N | GND | TX3N | GND | TX4N | GND | TX5N | GND | TX6N | GND | GND | J |
| н | TX0N | GND | TX1P | GND | TX2P | GND | ТХ3Р | GND | TX4P | GND | TX5P | GND | TX6P | GND | TX7N | н |
| G | TX0P | GND | GND | GND | GND | GND | GND | GND | GND | GND | GND | GND | GND | GND | TX7P | G |
| F | GND | GND | READ _EN_ N | SDC | GND | VDD | GND | VDD | GND | VDD | GND | GND | INT_N (NC) | GND | GND | F |
| Е | CAL_ CLK_ OUT | TEST 1 | ADDR 1 | SDA | GND | VDD | VDD | VDD | VDD | VDD | VDD | GND | EN_S MB | TEST 0 | CAL_ CLK_ IN | E |
| D | GND | GND | ADDR 0 | GND | GND | VDD | GND | VDD | GND | VDD | GND | GND | ALL_ DONE _N | GND | GND | D |
| С | RX0P | GND | GND | GND | GND | GND | GND | GND | GND | GND | GND | GND | GND | GND | RX7P | с |
| в | RX0N | GND | RX1P | GND | RX2P | GND | RX3P | GND | RX4P | GND | RX5P | GND | RX6P | GND | RX7N | в |
| Α | GND | GND | RX1N | GND | RX2N | GND | RX3N | GND | RX4N | GND | RX5N | GND | RX6N | GND | GND | А |
| | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | |



Pin Functions

| PIN | | 1/0 | DESCRIPTION | | | |
|------------|--------------|--------|--|--|--|--|
| NAME | NO. | 10 | DESCRIPTION | | | |
| HIGH SPEED | DIFFERENTIAL | . I/O | | | | |
| RX0N | B15 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100- Ω termination | | | |
| RX0P | C15 | Input | assembled on the package substrate. | | | |
| RX1N | A13 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100- Ω termination | | | |
| RX1P | B13 | Input | assembled on the package substrate. | | | |
| RX2N | A11 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100- Ω termination | | | |
| RX2P | B11 | Input | assembled on the package substrate. | | | |
| RX3N | A9 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100- Ω termination | | | |
| RX3P | B9 | Input | assembled on the package substrate. | | | |
| RX4N | A7 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100- Ω termination | | | |
| RX4P | B7 | Input | assembled on the package substrate. | | | |
| RX5N | A5 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100- Ω termination | | | |
| RX5P | B5 | Input | resistor connects RXP to RXN. These inputs are AC coupled with 220-nF capacitors assembled on the package substrate. | | | |
| RX6N | A3 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100- Ω termination | | | |
| RX6P | B3 | Input | assembled on the package substrate. | | | |
| RX7N | B1 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100- Ω termination | | | |
| RX7P | C1 | Input | assembled on the package substrate. | | | |
| TX0N | H15 | Output | Inverting and non-inverting 50- Ω driver outputs. Compatible with AC-coupled differential | | | |
| TX0P | G15 | Output | inputs. | | | |
| TX1N | J13 | Output | Inverting and non-inverting 50- Ω driver outputs. Compatible with AC-coupled differential | | | |
| TX1P | H13 | Output | inputs. | | | |

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Pin Functions (continued)

| PIN | | 1/0 | DESCRIPTION | | | |
|-----------------|------------|-------------------------------------|--|--|--|--|
| NAME | NO. | 1/0 | DESCRIPTION | | | |
| TX2N | J11 | Output | Inverting and non-inverting 50- Ω driver outputs. Compatible with AC-coupled differential | | | |
| TX2P | H11 | Output | inputs. | | | |
| TX3N | J9 | Output | Inverting and non-inverting 50- Ω driver outputs. Compatible with AC-coupled differential | | | |
| ТХЗР | H9 | Output | inputs. | | | |
| TX4N | J7 | Output | Inverting and non-inverting 50- Ω driver outputs. Compatible with AC-coupled differential | | | |
| TX4P | H7 | Output | inputs. | | | |
| TX5N | J5 | Output | Inverting and non-inverting 50- Ω driver outputs. Compatible with AC-coupled differential | | | |
| TX5P | H5 | Output | inputs. | | | |
| TX6N | J3 | Output | Inverting and non-inverting 50- Ω driver outputs. Compatible with AC-coupled differential | | | |
| TX6P | H3 | Output | inputs. | | | |
| TX7N | H1 | Output | Inverting and non-inverting 50- Ω driver outputs. Compatible with AC-coupled differential | | | |
| TX7P | G1 | Output | inputs. | | | |
| CALIBRATION | CLOCK PINS | (FOR SUPPOR | RTING UPGRADE PATH TO PIN-COMPATIBLE RETIMER DEVICE) | | | |
| CAL_CLK_IN | E1 | Input | 25-MHz (±100 PPM) 2.5-V single-ended clock from external oscillator. No stringent phase noise or jitter requirements on this clock. <i>A 25-MHz input clock is only required if there is a need to support a future upgrade to the pin-compatible Retimer device.</i> If there is no need to support a future upgrade to a pin-compatible Retimer device, then a 25-MHz clock is not required. This input pin has a weak active pull-down and can be left floating if the CAL_CLK feature is not required. | | | |
| CAL_CLK_ OUT | E15 | Output | 2.5-V buffered replica of calibration clock input (pin E1) for connecting multiple devices in a daisy-chained fashion. | | | |
| SYSTEM MAN | AGEMENT BU | S (SMBus) PIN | S | | | |
| ADDR0 | D13 | Input, 4-Level | 4-level strap pins used to set the SMBus address of the device. The pin state is read on | | | |
| ADDR1 | E13 | Input, 4-Level | power-up. The multi-level nature of these pins allows for 16 unique device addresses. The four strap options include: 0: 1 kΩ to GND R: 10 kΩ to GND F: Float 1: 1 kΩ to VDD | | | |
| ALL_DONE_ N | D3 | Output, LVCMOS | Indicates the completion of a valid EEPROM register load operation when in SMBus master mode (EN_SMB = Float): High = External EEPROM load failed or incomplete. Low = External EEPROM load successful and complete. When in SMBus slave mode (EN_SMB = 1 k Ω to VDD), this output will be high-Z until READ_EN_N is driven low, at which point ALL_DONE_N will be driven low. This behavior allows the reset signal connected to READ_EN_N of one device to propagate to the subsequent devices when ALL_DONE_N is connected to READ_EN_N in an SMBus slave mode application. | | | |
| EN_SMB | E3 | Input, 4-Level | 4-level 2.5-V input used to select between SMBus master mode (float) and SMBus slave mode (high). The four defined levels are: 0: 1 kΩ to GND - RESERVED R: 10 kΩ to GND - RESERVED F: Float - SMBus master mode 1: 1 kΩ to VDD - SMBus slave mode | | | |
| READ_EN_N | F13 | Input, LVCMOS | Pin has weak pull-up. This pin is 3.3 V tolerant. SMBus master mode (EN_SMB = Float): When asserted low, initiates the SMBus master mode EEPROM read function. Once EEPROM read is complete (indicated by assertion of ALL_DONE_N low), this pin can be held low for normal device operation. SMBus slave mode (EN_SMB = 1 k Ω to VDD): When asserted low, this causes the device to be held in reset (SMBus state machine reset and register reset). This pin should be pulled high or left floating for normal operation in SMBus slave mode. | | | |
| SDA | E12 | I/O, 3.3-V LVCMOS, Open Drain | SMBus data input and open drain output. External 2-k Ω to 5-k Ω pull-up resistor is required. This pin is 3.3-V LVCMOS tolerant. | | | |



Pin Functions (continued)

| PIN | | 1/0 | DESCRIPTION | | | | |
|------------|---|-------------------------------------|--|--|--|--|--|
| NAME | NO. | 1/0 | DESCRIPTION | | | | |
| SDC | F12 | I/O, 3.3-V LVCMOS, Open Drain | SMBus clock input and open drain clock output. External 2-k Ω to 5-k Ω pull-up resistor is required. This pin is 3.3-V LVCMOS tolerant. | | | | |
| MISCELLANE | OUS PINS | | | | | | |
| INT_N | F3 | No Connect | No connect on package. For applications using multiple repeaters and retimers, this pin should be connected to other devices' INT_N pins. This is only a recommendation for cases where there is a need to support a potential future upgrade to the pin-compatible retimer device, which uses this pin as an interrupt signal to a system controller. | | | | |
| TEST0 | E2 | Input, LVCMOS | Reserved test pin. During normal (non-test-mode) operation, this pin is configured as an | | | | |
| TEST1 | E14 | Input, LVCMOS | tied to GND, or connected to a 2.5-V (max) output. | | | | |
| POWER | | | | | | | |
| GND | $\begin{array}{c} \text{A1, A2, A4,} \\ \text{A6, A8, A10,} \\ \text{A12, A14,} \\ \text{A15, B2, B4,} \\ \text{B6, B8, B10,} \\ \text{B12, B14,} \\ \text{C2, C3, C4,} \\ \text{C5, C6, C7,} \\ \text{C8, C9, C10,} \\ \text{C11, C12,} \\ \text{C13, C14,} \\ \text{D1, D2, D4,} \\ \text{D5, D7, D9,} \\ \text{D11, D12,} \\ \text{D14, D15,} \\ \text{E4, E11, F1,} \\ \text{F2, F4, F5,} \\ \text{F7, F9, F11,} \\ \text{F14, F15,} \\ \text{G2, G3, G4,} \\ \text{G5, G6, G7,} \\ \text{G8, G9, G10,} \\ \text{G11, G12,} \\ \text{G13, G14,} \\ \text{H2, H4, H6,} \\ \text{H8, H10,} \\ \text{H12, H14, J1,} \\ \text{J2, J4, J6,} \\ \text{J8, J10, J12,} \\ \text{J14, J15} \\ \end{array}$ | Power | Ground reference. The GND pins on this device should be connected through a low- impedance path to the board GND plane. | | | | |
| VDD | D6, D8, D10, E5, E6, E7, E8, E9, E10, F6, F8, F10 | Power | Power supply, VDD = 2.5 V ±5%. Use at least six de-coupling capacitors between the Repeater's VDD plane and GND as close to the Repeater as possible. For example, four 0.1- μ F capacitors and two 1- μ F capacitors directly beneath the device or as close to the VDD pins as possible. The VDD pins on this device should be connected through a low-resistance path to the board VDD plane. For more information, see <i>Power Supply Recommendations</i> . | | | | |

6 Specifications

6.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted). (1)

| | | MIN | MAX | UNIT |
|----------------------------|--|------|------|------|
| VDD _{ABSMAX} | Supply voltage (VDD) | -0.5 | 2.75 | V |
| VIO _{2.5V,ABSMAX} | 2.5 V I/O voltage (LVCMOS and CMOS) | -0.5 | 2.75 | V |
| VIO _{3.3V,ABSMAX} | Open drain and 3.3 V-tolerance I/O voltage (SDA, SDC, READ_EN_N) | -0.5 | 4 | V |
| VIO _{HS,ABSMAX} | High-speed I/O voltage (RXnP, RXnN, TXnP, TXnN) | -0.5 | 2.75 | V |
| TJ _{ABSMAX} | Junction temperature | | 150 | °C |
| T _{stg} | Storage temperature | -40 | 150 | °C |

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|--|-------|------|
| | | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | |
| V _(ESD) | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 $\scriptstyle (2)$ | ±750 | V |

 JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Pins listed as ±2 kV may actually have higher performance.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted).

| | | | MIN | NOM | MAX | UNIT |
|----------------------|---|--|-------|-----|-------|------|
| VDD | Supply voltage, VDD to GND | DC plus AC power should not exceed these limits | 2.375 | 2.5 | 2.625 | V |
| | | Supply noise, DC to <50 Hz, sinusoidal | | | 250 | mVpp |
| N _{VDD} | Supply noise tolerance ⁽¹⁾ | Supply noise, 50 Hz to 10 MHz, sinusoidal | | | 20 | mVpp |
| | | Supply noise, >10 MHz, sinusoidal | | | 10 | mVpp |
| T _{RampVDD} | VDD supply ramp time | From 0 V to 2.375 V | 150 | | | μs |
| TJ | Operating junction temperature | | -40 | | 110 | С |
| T _A | Operating ambient temperature | | -40 | | 85 | С |
| VDD _{SMBUS} | SMBus SDA and SDC Open Drain Termination Voltage | Supply voltage for open drain pull-up resistor | | | 3.6 | V |
| F _{SMBus} | SMBus clock (SDC) frequency in SMBus slave mode | | | | 400 | kHz |

(1) Sinusoidal noise is superimposed to supply voltage with negligible impact to device function or critical performance shown in the Electrical Table.

6.4 Thermal Information

| | THERMAL METRIC ⁽¹⁾ | CONDITIONS / ASSUMPTIONS | VALUE | UNIT | | | |
|-----------------------|--|---------------------------------|-------|-------|--|--|--|
| | | 4-layer JEDEC board | 45.2 | | | | |
| 5 | | 10-layer 8-in x 6-in board | 26.3 | 00.00 | | | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 20-layer 8-in x 6-in board | 24.8 | °C/W | | | |
| | | 30-layer 8-in x 6-in board | 22.7 | | | | |
| R _{0JC(top)} | Junction-to-case (top) thermal resistance | 4-layer JEDEC board | 26.6 | °C/W | | | |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 4-layer JEDEC board | 25.8 | °C/W | | | |
| | | 4-layer JEDEC board | 13.3 | | | | |
| | | 10-layer 8-in x 6-in board | 13.0 | 0000 | | | |
| ΨJT | Junction-to-top characterization parameter | 20-layer 8-in x 6-in board | 13.0 | °C/W | | | |
| | | 30-layer 8-in x 6-in board | 13.0 | | | | |
| | | 4-layer JEDEC board | 22.8 | | | | |
| | | 10-layer 8-in x 6-in board | 21.4 | 0000 | | | |
| Ψјв | Junction-to-board characterization parameter | 20-layer 8-in x 6-in board | 21.1 | °C/W | | | |
| | | 30-layer 8-in x 6-in board | 20.8 | - | | | |

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Electrical Characteristics

Over operating free-air temperature range (unless otherwise noted).

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------|---|--|-----|-----|--------------------|------|
| POWER | | | | | | |
| W _{channel} | | Channel enabled and in linear mode with maximum driver VOD (DRV_SEL_VOD = 3). Static power consumption not included. | | 82 | 97 ⁽¹⁾ | mW |
| | Power consumption per active channel | Channel enabled and in linear mode with minimum driver VOD (DRV_SEL_VOD = 0). Static power consumption not included. | | 75 | 89 ⁽¹⁾ | mW |
| W _{channel_} FIR | Power consumption per active channel | Channel enabled and in FIR limiting mode with C0 = 31 and maximum driver VOD (DRV_SEL_VOD = 3). Static power consumption not included. | | 105 | 123 ⁽¹⁾ | mW |
| | Power consumption per active channel | Channel enabled and in FIR limiting mode with C0 = 31 and minimum driver VOD (DRV_SEL_VOD = 0). Static power consumption not included. | | 97 | 115 ⁽¹⁾ | mW |
| W _{static_total} | Idle (static) mode total device power consumption | Channels disabled and powered down (DRV_PD = 1, EQ_PD = 1). | | 110 | 132 ⁽¹⁾ | mW |
| I _{total} | Active mode total device supply | All channels enabled and in linear mode with maximum driver VOD (DRV_SEL_VOD = 3). | | 307 | 347 | mA |
| | current consumption | All channels enabled and in linear mode with minimum driver VOD (DRV_SEL_VOD = 0). | | 283 | 322 | mA |

(1) Max values assume VDD = 2.5 V + 5%.

ISTRUMENTS

EXAS

Electrical Characteristics (continued)

Over operating free-air temperature range (unless otherwise noted).

| | PARAMETER | TEST CONDITIONS | MIN | ТҮР | MAX | UNIT |
|---------------------------|--|---|----------|---------------|---|---------|
| | Active mode total device supply | All channels enabled and in FIR limiting mode with C0 = 31 and maximum driver VOD (DRV_SEL_VOD = 3). | | 380 | 426 | mA |
| Itotal_FIR | current consumption | All channels enabled and in FIR limiting mode with C0 = 31 and minimum driver VOD (DRV_SEL_VOD = 0). | | 355 | 426 401 50 VDD 3.6 0.7 0.4 16 66 1 1 DR1, and 1 105 | mA |
| I _{static_total} | Idle (static) mode total device supply current consumption | All channels disabled and powered down (DRV_PD = 1, EQ_PD = 1). | | 44 | 50 | mA |
| LVCMOS DC | SPECIFICATIONS (CAL_CLK_IN, CAL | _CLK_OUT, READ_EN_N, ALL_DONE_ | N, TEST[| 1:0]) | | |
| Maria | High lovel input veltage | | 1.75 | | VDD | V |
| VН | High level input voltage | READ_EN_N pin only | 1.75 | | 3.6 | V |
| VIL | Low level input voltage | | GND | | 0.7 | V |
| V _{OH} | High level output voltage | IOH = 4 mA | 2 | | | V |
| V _{OL} | Low level output voltage | IOL = -4 mA | | | 0.4 | V |
| Ін | | Vinput = VDD, TEST[1:0] pins | | | 16 | μΑ |
| | Input high leakage current | Vinput = VDD, CAL_CLK_IN pin | | | 66 | μΑ |
| | | Vinput = VDD, READ_EN_N pin (2) | | | 1 | μΑ |
| | | Vinput = 0 V, TEST[1:0] pins | -38 | | | μΑ |
| I _{IL} | Input low leakage current | Vinput = 0 V, CAL_CLK_IN pin ⁽³⁾ | -1 | | | μA |
| | | Vinput = 0 V, READ_EN_N pin $^{(2)}$ | -55 | | | μA |
| 4-LEVEL LOO | GIC ELECTRICAL SPECIFICATIONS (A | PPLIES TO 4-LEVEL INPUT CONTROL | PINS AD | DR0, ADD | R1, and E | EN_SMB) |
| I _{IH} | Input high leakage current | | | | 105 | μΑ |
| IIL | Input low leakage current | | -253 | | | μA |
| | High level (1) input voltage | | | 0.95 × VDD | | V |
| VTH | Float level input voltage | | | 0.67 × VDD | | V |
| | 10 K to GND input voltage | | | 0.33 × VDD | | V |
| | Low level (0) input voltage | | | 0.1 | | V |
| HIGH-SPEED | DIFFERENTIAL INPUTS (RXnP, RXnN |) | | | | |
| BST | CTLE high-frequency boost | Measured with maximum CTLE setting and maximum BW setting (EQ_BST1 = 7, EQ_BST2 = 7, EQ_BW = 3). Boost is defined as the gain at 14 GHz relative to 20 MHz. | | 25.6 | | dB |
| BST | CTLE high-nequency boost | Measured with maximum CTLE setting and maximum BW setting (EQ_BST1 = 7, EQ_BST2 = 7, EQ_BW = 3). Boost is defined as the gain at 12.9 GHz relative to 20 MHz. | | 25.3 | | dB |

This pin has an internal weak pull-up. This pin has an internal weak pull-down. (2)

(3)

8 Submit Documentation Feedback



Electrical Characteristics (continued)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|---|---|-----|-------|-----|------|
| Det | CTI E high frequency boost | Measured with minimum CTLE setting and minimum BW setting (EQ_BST1 = 0, EQ_BST2 = 0, EQ_BW = 0, EQ_EN_BYPASS = 1). Boost is defined as the gain at 14 GHz relative to 20 MHz. | | 2.4 | | dB |
| 551 | | Measured with minimum CTLE setting and minimum BW setting (EQ_BST1 = 0, EQ_BST2 = 0, EQ_BW = 0, EQ_EN_BYPASS = 1). Boost is defined as the gain at 12.9 GHz relative to 20 MHz. | | 2.4 | | dB |
| PST | CTI E high frequency gain variation | Measured with maximum CTLE setting (EQ_BST1 = 7, EQ_BST2 = 7). Gain variation is defined as the total change in gain at 14 GHz due to temperature and voltage variation. | | < 3 | | dB |
| BST _{delta} | CILE ligh-nequency gain variation | Measured with maximum CTLE setting (EQ_BST1 = 7, EQ_BST2 = 7). Gain variation is defined as the total change in gain at 12.9 GHz due to temperature and voltage variation. | | < 3 | | dB |
| BST _{delta} | CTI E high frequency goin variation | Measured with minimum CTLE setting $(EQ_BST1 = 0, EQ_BST2 = 0, EQ_EN_BYPASS = 1)$. Gain variation is defined as the total change in gain at 14 GHz due to temperature and voltage variation. | | < 2 | | dB |
| | CILE high-frequency gain variation | Measured with minimum CTLE setting $(EQ_BST1 = 0, EQ_BST2 = 0, EQ_EN_BYPASS = 1)$. Gain variation is defined as the total change in gain at 12.9 GHz due to temperature and voltage variation. | | < 2 | | dB |
| | | 50 MHz to 3.7 GHz | | < -14 | | dB |
| | | 3.7 GHz to 10 GHz | | < -12 | | dB |
| RL _{SDD11} | Input differential return loss | 10 GHz to 14.1 GHz | | < -8 | | dB |
| | | 14.1 GHz to 20 GHz | | < -6 | | dB |
| | | 100 MHz to 3.3 GHz | | < -35 | | dB |
| RL _{SDC11} | Input differential-to-common-mode | 3.3 GHz to 12.9 GHz | | < -26 | | dB |
| | 1610111033 | 12.9 GHz to 20 GHz | | < -22 | | dB |
| DI | | 100 MHz to 10 GHz | | < -7 | | dB |
| KLSCC11 | input common-mode return ioss | 10 GHz to 20 GHz | | < -8 | | dB |
| V _{SDAT} | AC signal detect assert (ON) differential voltage threshold level | Minimum input peak-to-peak amplitude level at device pins required to assert signal detect. 25.78125 Gbps with PRBS7 pattern and 20 dB loss channel. | | 196 | | mVpp |
| V _{SDDT} | AC signal detect de-assert (OFF) differential voltage threshold level | Maximum input peak-to-peak amplitude level at device pins which causes signal detect to de-assert. 25.78125 Gbps with PRBS7 pattern and 20 dB loss channel. | | 147 | | mVpp |

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Electrical Characteristics (continued)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------------|--|---|-----|------|-----|------|
| | | Measured with the highest wide-band gain setting (EQ_HIGH_GAIN = 1, DRV_SEL_VOD = 3). Measured with minimal input channel and minimum EQ using a 1 GHz signal. | | 850 | | mVpp |
| VID | Input amplitude linear range. The | Measured with a mid wide-band gain setting (EQ_HIGH_GAIN = 1, DRV_SEL_VOD = 0). Measured with minimal input channel and minimum EQ using a 1 GHz signal. | | 900 | | mVpp |
| ViDlinear | remains linear, defined as ≤1 dB compression of Vout/Vin. | Measured with a mid wide-band gain setting (EQ_HIGH_GAIN = 0, DRV_SEL_VOD = 3). Measured with minimal input channel and minimum EQ using a 1 GHz signal. | | 1050 | | mVpp |
| | | Measured with the lowest wide-band gain setting (EQ_HIGH_GAIN = 0, DRV_SEL_VOD = 0). Measured with minimal input channel and minimum EQ using a 1 GHz signal. | | 1250 | | mVpp |
| HIGH-SPEED | DIFFERENTIAL OUTPUTS (TXnP, TXn | N) | | | | |
| PRE _{DEM-MAX} | Maximum pre-cursor de-emphasis in FIR limiting mode | Measured with an 16T pattern at 28.125 Gbps using C(0), Reg_0x0B[4:0], set to 0x0C, C(-1), Reg_0x0D[3:0], set to 0xF, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. | | -11 | | dB |
| PST _{DEM-MAX} | Maximum post-cursor de-emphasis in FIR limiting mode | Measured with an 16T pattern at 28.125 Gbps using C(0), Reg_0x0B[4:0], set to 0x0C, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0xF. TX drv_sel_fir, Reg_0x06[0], set to 0x1. | | -11 | | dB |
| T _{PRE} | Pre-cursor FIR tap delay in FIR limiting mode | Independent of data rate | | 28 | | ps |
| T _{PST} | Post-cursor FIR tap delay in FIR limiting mode | Independent of data rate | | 25 | | ps |
| VOD _{LIM-MIN} | Minimum differential output amplitude | Measured with a 16T pattern at 25.78125 Gbps using C(0), Reg_0x0B[4:0], set to 0x00, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. VOD, Reg_0x06[7:6], set to 0x0. | | 185 | | mVpp |
| | in FIR limiting mode | Measured with a 16T pattern at 25.78125 Gbps using C(0), Reg_0x0B[4:0], set to 0x00, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. VOD, Reg_0x06[7:6], set to 0x3. | | 360 | | mVpp |



Electrical Characteristics (continued)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT | |
|---------------------------------|---|---|------|-------|------|----------|--|
| VOD | Maximum differential output amplitude | Measured with a 16T pattern at 25.78125 Gbps using C(0), Reg_0x0B[4:0], set to 0x1F, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. VOD, Reg_0x06[7:6], set to 0x0. | | 705 | | mVpp | |
| VOD _{LIM-MAX} | in FIR limiting mode | Measured with a 16T pattern at 25.78125 Gbps using C(0), Reg_0x0B[4:0], set to 0x1F, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. VOD, Reg_0x06[7:6], set to 0x3. | | 1260 | | mVpp | |
| VOD _{idle} | Differential output amplitude, TX disabled or otherwise muted | | | < 10 | | mVpp | |
| Gnc | Vout/Vin wide-band amplitude gain in | Measured with the highest wide-band gain setting (EQ_HIGH_GAIN = 1, DRV_SEL_VOD = 3) at 20 MHz. | | 4.5 | | dB | |
| GDC | linear mode | Measured with the lowest wide-band gain setting (EQ_HIGH_GAIN = 0, DRV_SEL_VOD = 0) at 20 MHz. | | -5 | | | |
| V _{cm-TX-AC} | Common-mode AC output noise | Defined as (TXP + TXN)/2. Measured with a low-pass filter with 3-dB bandwidth at 33 GHz. | | 6 | | mV, RMS | |
| V _{cm-TX-DC} | Common-mode DC output | Defined as (TXP + TXN)/2. Measured with a DC signal. | 0.75 | 0.96 | 1.05 | V | |
| RJ _{ADD-RMS} | Additive random jitter | Measured single-endedly on a Keysight E5505A phase noise measurement solution with a 28-Gbps 1010 pattern, from 2 kHz to 20 MHz. | | 11 | | fs RMS | |
| | | 50 MHz to 4.8 GHz | | < -16 | | | |
| | Output differential-to-differential return | 4.8 GHz to 10 GHz | | < -15 | | -ID | |
| RL _{SDD22} | loss | 10 GHz to 14.1 GHz | | <8 | | dВ | |
| | | 14.1 GHz to 20 GHz | | <8 | | | |
| | | 50 MHz to 6.0 GHz | | <21 | | | |
| | Output common-mode-to-differential | 6.0 GHz to 12.9 GHz | | < -22 | | | |
| RL _{SCD22} | return loss | 12.9 GHz to 14.1 GHz | | <21 | | dB | |
| | | 14.1 GHz to 20 GHz | | < -20 | | | |
| | | 50 MHz to 3.3 GHz | | < -13 | | | |
| RL _{SCC22} | Output common-mode return loss | 3.3 GHz to 10.3 GHz | | < -11 | | dB | |
| | | 10.3 GHz to 20 GHz | | < -9 | | | |
| t _r , t _f | Transition time (20%-80%) in FIR | Measured at 28.125 Gbps with 16T data pattern using C(0), Reg_0x0B[4:0], set to 0x00, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. | | 19.9 | | ps ps | |
| | limiting mode | Measured at 28.125 Gbps with 16T data pattern using C(0), Reg_0x0B[4:0], set to 0x1F, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. | | 25.8 | | | |

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Electrical Characteristics (continued)

Over operating free-air temperature range (unless otherwise noted).

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------------------|---|--|-----|-----|-----|------|
| OTHER PAR | AMETERS | | | | | |
| t _D | Input-to-output latency (propagation delay) through a channel | Linear mode | | 100 | | ps |
| t _D | Input-to-output latency (propagation delay) through a channel | FIR limiting mode, Reg_0x06[0]=1 | | 160 | | ps |
| t _{SK} | Channel-to-channel interpair skew | Latency difference between channels. | | <14 | | ps |
| T _{EEPROM} EEPROM con | EEDDOM configuration load time | Time to assert ALL_DONE_N after REAN_EN_N has been asserted. Single device reading its configuration from an EEPROM with common channel configuration. This time scales with the number of devices reading from the same EEPROM. Does not include power-on reset time. | | | 4 | |
| | | Time to assert ALL_DONE_N after REAN_EN_N has been asserted. Single device reading its configuration from an EEPROM. Non- common channel configuration. This time scales with the number of devices reading from the same EEPROM. Does not include power-on reset time. | | | 7 | ms |
| T _{POR} | Power-on reset assertion time | Internal power-on reset (PoR) stretch between stable power supply and de- assertion of internal PoR. The SMBus address is latched on the completion of the PoR stretch, and SMBus accesses are permitted once PoR completes. | | | 60 | ms |

6.6 Electrical Characteristics – Serial Management Bus Interface

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------|--------------------------|---------------------------------------|------|-----|-----|------|
| VIH | Input high level voltage | SDA and SDC | 1.75 | | 3.6 | V |
| VIL | Input low level voltage | SDA and SDC | GND | | 0.8 | V |
| V _{OL} | Output low level voltage | SDA and SDC, I_{OL} = 1.25 mA | GND | | 0.4 | V |
| CIN | Input pin capacitance | SDA and SDC | | 15 | | pF |
| I _{IN} | Input current | SDA or SDC, VINPUT = VIN, VDD, GND | -18 | | 18 | μA |

6.7 Timing Requirements – Serial Management Bus Interface

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT | | | |
|-----------------------|--|--|------|------|------|------|--|--|--|
| RECOMMEN | RECOMMENDED SMBus SWITCHING CHARACTERISTICS (SMBus SLAVE MODE) | | | | | | | | |
| f _{SDC} | SDC clock frequency | EN_SMB = 1 k to VDD (Slave Mode) | 10 | 100 | 400 | kHz | | | |
| T _{SDA-HD} | Data hold time | | | 0.75 | | ns | | | |
| T _{SDA-SU} | Data setup time | | | 100 | | ns | | | |
| T _{SDA-R} | SDA rise time, read operation | Pull-up resistor = 1 k Ω , Cb = 50 pF | | 150 | | ns | | | |
| T _{SDA-F} | SDA fall time, read operation | Pull-up resistor = 1 k Ω , Cb = 50 pF | | 4.5 | | ns | | | |
| SMBus SWIT | CHING CHARACTERISTICS (SMBus M | ASTER MODE) | | | | | | | |
| f _{SDC} | SDC clock frequency | EN_SMB = Float (Master Mode) | 260 | 303 | 346 | kHz | | | |
| T _{SDC-LOW} | SDC low period | | 1.66 | 1.90 | 2.21 | μs | | | |
| T _{SDC-HIGH} | SDC high period | | 1.22 | 1.40 | 1.63 | μs | | | |
| T _{HD-START} | Hold time start operation | | | 0.6 | | μs | | | |



Timing Requirements – Serial Management Bus Interface (continued)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT | | |
|-----------------------|----------------------------------|---------------------------------|-----|-----|-----|------|--|--|
| T _{SU-START} | Setup time start operation | | | 0.6 | | μs | | |
| T _{SDA-HD} | Data hold time | | | 0.9 | | μs | | |
| T _{SDA-SU} | Data setup time | | | 0.1 | | μs | | |
| T _{SU-STOP} | Stop condition setup time | | | 0.6 | | μs | | |
| T _{BUF} | Bus free time between Stop-Start | | | 1.3 | | μs | | |
| T _{SDC-R} | SDC rise time | Pull-up resistor = 1 k Ω | | 300 | | ns | | |
| T _{SDC-F} | SDC fall time | Pull-up resistor = 1 k Ω | | 300 | | ns | | |

Over operating free-air temperature range (unless otherwise noted).

6.8 Typical Characteristics







7 Detailed Description

7.1 Overview

The DS280BR820 is an eight-channel multi-rate linear repeater with integrated signal conditioning. The eight channels operate independently from one another. Each channel includes a continuous-time linear equalizer (CTLE), an optional FIR filter and a linear output driver, which compensate for the presence of a dispersive transmission channel between the source transmitter and the final receiver.

All receive channels on the DS280BR820 are AC-coupled with physical AC coupling capacitors (220 nF ±20%) on the package substrate. This ensures common mode voltage compatibility with all link partner transmitters and eliminates the need for AC coupling capacitors on the system PCB, thereby saving cost and greatly reducing PCB routing complexity.

The DS280BR820 is configurable through a single SMBus port. The DS280BR820 can also act as an SMBus master to configure itself from an EEPROM.

NOTE

The DS280BR820 offers improved high-frequency boost and bandwidth compared to the DS280BR810. The DS280BR810 has series AC coupling capacitors on both the RX and TX pins, whereas the DS280BR820 has series AC coupling capacitors on the RX inputs only. The DS280BR820 and DS280BR810 are otherwise pin-to-pin compatible and share the same register programming interface.

The sections which follow describe the functionality of various circuits and features within the DS280BR820. For more information about how to program or operate these features, consult the DS280BR820 Programming Guide.

7.2 Functional Block Diagram





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7.3 Feature Description

7.3.1 Device Data Path Operation

The DS280BR820 data path consists of several key blocks as shown in *Functional Block Diagram*. These key circuits are:

- AC-Coupled Receiver Inputs
- Signal Detect
- 2-Stage CTLE
- Driver DC Gain Control
- FIR Filter (Limiting Mode)
- Configurable SMBus Address

7.3.2 AC-Coupled Receiver Inputs

The differential receiver for each DS280BR820 channel contains an integrated on-die 100- Ω differential termination as well as 220-nF ±20% series AC coupling capacitors embedded onto the package substrate.

7.3.3 Signal Detect

Each DS280BR820 high speed receiver has a signal detect circuit which monitors the energy level on the inputs. The signal detect circuit will enable the high-speed data path if a signal is detected, or power it off if no signal is detected. By default, this feature is enabled, but can be manually controlled though the SMBus channel registers. This can be useful if it is desired to manually force channels to be disabled. For information on how to manually operate the signal detect circuit refer to the DS280BR820 Programming Guide.

7.3.4 2-Stage CTLE

The continuous-time linear equalizer (CTLE) in the DS280BR820 consists of two stages which are configurable via the SMBus channel registers. This CTLE is designed to be highly linear to allow the DS280BR820 to preserve the transmitter's pre-cursor and post cursor signal characteristics. This highly linear behavior enables the DS280BR820 to be used in applications that use protocols such as link training, where it is important to recover and pass through incremental changes in transmit equalization.

Each stage in the CTLE has 3-bit boost control. The first CTLE stage provides a coarse adjustment of the total boost. Larger settings correspond to higher total boost. The first stage can be bypassed entirely to achieve the lowest possible total boost. The second CTLE stage acts as a fine adjustment on the total boost and impacts the shape of the boost curve accordingly. Larger settings correspond to higher total boost. The bandwidth of the CTLE can be adjusted using a 2-bit bandwidth control. Larger settings correspond to higher total bandwidth. For information on how to program the CTLE refer to the DS280BR820 Programming Guide.

In addition to high-frequency boost, the CTLE can apply wide-band amplitude gain. There are two settings (highgain and low-gain) which work together with the driver DC gain control to affect the total input-to-output wideband amplitude gain.

7.3.5 Driver DC Gain Control

In addition to the high-frequency boost provided by the CTLE, the DS280BR820 is also able to provide additional DC or low-frequency gain. The effective DC gain is controlled by a 3-bit field, allowing for eight levels of DC attenuation or DC gain. For information on how to configure the DC gain refer to the DS280BR820 Programming Guide.

7.3.6 FIR Filter (Limiting Mode)

The DS280BR820 has an optional limiting mode with a fixed-delay 3-tap finite impulse response (FIR) filter to provide transmit equalization. This FIR can be configured to apply pre-cursor and post-cursor boost to the high speed signal. The FIR filter also allows for main cursor amplitude control. The tap polarities in the FIR filter are fixed to allow for pre-cursor or post-cursor boost to be applied to the signal.



Feature Description (continued)



Figure 4. 3-Tap FIR Filter Block Diagram

Linear mode is recommended for the majority of applications, especially those which require Link Training. Common protocols such as 100 GbE and 40 GbE CR4/KR4, 50 GbE and 25 GbE CR, 10 GbE KR, InfiniBand EDR, and others require Link Training. Linear mode is required for Link Training so that the ASIC transmitter precursor and post-cursor coefficients can propagate through the DS280BR820 in a transparent fashion. For applications which do not utilize Link Training, limiting mode may be used to provide output pre-cursor and postcursor equalization for the purpose of improving the far-end eye opening. If the downstream receiver SerDes uses a decision feedback equalizer (DFE) to equalize the signal, the linear mode may be preferable to the limiting mode. DFE circuits often perform best when operating on a linear signal.

7.3.7 Configurable SMBus Address

The DS280BR820's SMBus slave address is strapped at power up using the ADDR[1:0] pins. The pin state is read on power up, after the internal power-on reset completes. The ADDR[1:0] pins are four-level LVCMOS IOs, which provide for 16 unique SMBus addresses. Table 1 lists the DS280BR820 SMBus slave address options.

| | | REQUIRED ADDRESS PIN STRAP VALUE | | | |
|---------------------|---------------------|----------------------------------|-------|--|--|
| 7-BIT SLAVE ADDRESS | 6-BIT WRITE ADDRESS | ADDR1 | ADDR0 | | |
| 0x18 | 0x30 | 0 | 0 | | |
| 0x19 | 0x32 | 0 | R | | |
| 0x1A | 0x34 | 0 | F | | |
| 0x1B | 0x36 | 0 | 1 | | |
| 0x1C | 0x38 | R | 0 | | |
| 0x1D | 0x3A | R | R | | |
| 0x1E | 0x1E 0x3C | | F | | |
| 0x1F | 0x3E | R | 1 | | |
| 0x20 | 0x40 | F | 0 | | |
| 0x21 | 0x42 | F | R | | |
| 0x22 | 0x44 | F | F | | |
| 0x23 | 0x46 | F | 1 | | |
| 0x24 | 0x48 | 1 | 0 | | |
| 0x25 | 0x4A | 1 | R | | |
| 0x26 | 0x4C | 1 | F | | |
| 0x27 | 0x4E | 1 | 1 | | |

Table 1. SMBus Address Map



7.4 Device Functional Modes

7.4.1 SMBus Slave Mode Configuration

To configure the DS280BR820 for SMBus slave mode connect the EN_SMB pin to VDD with a 1 k Ω resistor. When the DS280BR820 is configured for SMBus slave mode operation the READ_EN_N becomes an active-low reset pin, resetting register values when driven to LOW, or V_{IL}. Additionally, when the DS280BR820 is configured for SMBus slave mode the ALL_DONE_N output pin is high-Z; except for when READ_EN_N is driven LOW which causes ALL_DONE_N to also be driven LOW. Refer to *Register Maps* for additional register information.

7.4.2 SMBus Master Mode Configuration (EEPROM Self Load)

To configure the DS280BR820 for SMBus master mode, leave the EN_SMB pin floating (no connect). If the DS280BR820 is configured for SMBus master mode, it will remain in the SMBus IDLE state until the READ_EN_N pin is asserted to LOW. Once the READ_EN_N pin is driven LOW, the DS280BR820 becomes an SMBus master and attempts to self-configure by reading device settings stored in an external EEPROM (SMBus 8-bit address 0xA0). When the DS280BR820 has finished reading from the EEPROM successfully, it will drive the ALL_DONE_N pin LOW and then change from an SMBus master to an SMBus slave. Not all bits in the register map can be configured through an EEPROM load. Refer to the Programming Guide for more information.

When designing a system for using the external EEPROM, the user must follow these specific guidelines:

- Maximum EEPROM size is 8 kb (1024 x 8-bit)
- Set EN_SMB = FLOAT, configure for SMBus master mode
- The external EEPROM device address byte must be 0xA0 and capable of 400 kHz operation at 2.5-V or 3.3-V supply.
- Configure the ADDR[1:0] inputs to select the SMBus slave address for the DS280BR820. Once the DS280BR820 completes its EEPROM load the device becomes a slave on the control bus.



Tie first device's READ_EN_N pin low to automatically initiate EEPROM read at power up, or control this pin from a device to initiate EEPROM read manually.

Leave final device's ALL_DONE_N pin floating or connect to a control chip to monitor completion of final EEPROM read.

Figure 5. Example Daisy Chain for Multiple Device Single EEPROM Configuration

When tying multiple DS280BR820 devices to the SDA and SDC bus, use these guidelines to configure the devices for SMBus master mode:

- Use SMBus ADDR[1:0] address bits so that each device can load its configuration from the EEPROM. The
 example below is for four devices. The first device in the sequence conventionally uses the 8-bit slave write
 address 0x30, while subsequent devices follow the address order listed below.
 - DS280BR820 instance 1 (U1): ADDR[1:0] = {0, 0} = 0x30
 - DS280BR820 instance 2 (U2): ADDR[1:0] = {0, R} = 0x32
 - DS280BR820 instance 3 (U3): ADDR[1:0] = {0, F} = 0x34
 - DS280BR820 instance 4 (U4): ADDR[1:0] = {0, 1} = 0x36
- Use a pull-up resistor on SDA and SDC; resistor value = $2 k\Omega$ to $5 k\Omega$ is adequate.
- Float (no connect) the EN_SMB pin (E3) on all DS280BR820 devices to configure them for SMBus master mode. The EN_SMB pin should not be dynamically changed between the high and float states.



Device Functional Modes (continued)

- Daisy-chain READ_EN_N (pin F13) and ALL_DONE_N (pin D3) from one device to the next device in the following sequence so that they do not compete for master control of the EEPROM at the same time.
 - 1. Tie READ_EN_N of the first device in the chain (U1) to GND to trigger EEPROM read immediately after the DS280BR820 power-on reset (PoR) completes. Alternatively, drive the READ_EN_N pin from a control device (micro-controller or FPGA) to trigger the EEPROM read at a specific time.
 - 2. Tie ALL_DONE_N of U1 to READ_EN_N of U2
 - 3. Tie ALL_DONE_N of U2 to READ_EN_N of U3
 - 4. Tie ALL_DONE_N of U3 to READ_EN_N of U4
 - 5. Optional: Tie ALL_DONE_N output of U4 to a micro-controller or an LED to show the devices have been loaded successfully.

Once the ALL_DONE_N status pin of the last device is flagged to indicate that all devices sharing the SMBus line have been successfully programmed, control of the SMBus line is released by the DS280BR820. The device then reverts back to SMBus slave mode. At this point, an external MCU can perform any additional Read or Write operations to the DS280BR820.

Refer to the Programming Guide for additional information concerning SMBus master mode.

7.5 Programming

The DS280BR820 can be programmed in two ways. The DS280BR820 can be configured as an SMBus slave (EN_SMB = HIGH) or the device can temporarily act as an SMBus master and load its configuration settings from an external EEPROM (EN_SMB = FLOAT). Refer to *SMBus Slave Mode Configuration* and *SMBus Master Mode Configuration (EEPROM Self Load)* for details.

7.5.1 Transfer of Data with the SMBus Interface

The System Management Bus (SMBus) is a two-wire serial interface through which a master can communicate with various system components. Slave devices are identified by a unique device address. The two-wire serial interface consists of SDC and SDA signals. SDC is a clock output from the master to all of the slave devices on the bus. SDA is a bidirectional data signal between the master and slave devices. The DS280BR820 SMBus SDC and SDA signals are open drain and require external pull-up resistors.

Start and Stop Conditions:

The master generates Start and Stop conditions at the beginning and end of each transaction:

- Start: HIGH to LOW transition (falling edge) of SDA while SDC is HIGH.
- Stop: LOW to HIGH transition (rising edge) of SDA while SDC is HIGH.

The master generates 9 clock pulses for each byte transfer. The 9th clock pulse constitutes the acknowledge (ACK) cycle. The transmitter releases SDA to allow the receiver to send the ACK signal. An ACK is when the device pulls SDA LOW, while a NACK (no acknowledge) is recorded if the line remains HIGH.

Writing data from a master to a slave consists of three parts:

- The master begins with a start condition followed by the slave device address with the R/W bit cleared.
- The master sends the 8-bit register address that will be written.
- The master sends the data byte to write for the selected register address. The register address pointer will then increment, so the master can send the data byte for the subsequent register without re-addressing the device, if desired. The final data byte to write should be followed by a stop condition.

SMBus read operations consist of four parts:

- The master initiates the read cycle with start condition followed by slave device address with the R/W bit cleared.
- The master sends the 8-bit register address that will be read.
- After acknowledgment from the slave, the master initiates a re-start condition.
- The slave device address is resent followed with R/W bit set.
- After acknowledgment from the slave, the data is read back from the slave to the master. The last ACK is HIGH if there are no more bytes to read.



7.6 Register Maps

Many of the registers in the DS280BR820 are divided into bit fields. This allows a single register to serve multiple purposes which may be unrelated. Often, configuring the DS280BR820 requires writing a bit field that makes up only part of a register value while leaving the remainder of the register value unchanged. The procedure for accomplishing this task is to read in the current value of the register to be written, modify only the desired bits in this value, and write the modified value back to the register. This sequence is commonly referred to as Read-Modify-Write. If the entire register is changed, rather than just a bit field within the register, it is not necessary to read in the current value of the register first.

Most register bits can be read or written to. However, some register bits are constrained to specific interface instructions.

Register bits can have the following interface constraints:

- R Read only
- RW Read/Write
- RWSC Read/Write, Self-Clearing

7.6.1 Register Types: Global, Shared, and Channel

The DS280BR820 has 3 types of registers:

- 1. Global Registers These registers can be accessed at any time and are used to select between individual channel registers and shared registers, or to read back the TI ID and version information.
- 2. Shared Registers These registers are used for device-level configuration, status read back or control. Set register 0xFF[0] = 0 and configure 0xFF[5:4] to access the shared registers.
- Channel Registers These registers are used to control and configure specific features for each individual channel. All channels have the same channel register set and can be configured independent of each other. Set register 0xFF[0] = 1 and configure register 0xFC to access the desired channel register set.

Refer to the Programming Guide for additional information on register configuration.

7.6.2 Global Registers: Channel Selection and ID Information

The global registers can be accessed at any time, regardless of whether the shared or channel register set is selected. The DS280BR820 global registers are located at address 0xEF - 0xFF.

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|---------------|-----|------------------|------|--------|---------------------------|---|
| 0xEF | | 0x0C | | | General | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 1 | R | N | DEVICE_ID_QUAD_ CNT[3] | TI device ID (quad count). Contains 0x0C. |
| | 2 | 1 | R | N | DEVICE_ID_QUAD_ CNT[2] | |
| | 1 | 0 | R | N | DEVICE_ID_QUAD_ CNT[1] | |
| | 0 | 0 | R | N | DEVICE_ID_QUAD_ CNT[0] | |

Table 2. Global Register Map

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Register Maps (continued)

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|---------------|----------|------------------|------|--------|------------------|---|
| 0xF0 | | 0x00 | | | Version Revision | |
| | 7 | 0 | R | N | TYPE | TI version ID. Contains 0x00. |
| | 6 | 0 | R | N | VERSION[6] | |
| | 5 | 0 | R | N | VERSION[5] | |
| | 4 | 0 | R | N | VERSION[4] | |
| | 3 | 0 | R | N | VERSION[3] | |
| | 2 | 0 | R | N | VERSION[2] | |
| | 1 | 0 | R | N | VERSION[1] | |
| | 0 | 0 | R | N | VERSION[0] | |
| 0xF1 | | 0x40 | | | Channel Control | |
| | 7 | 0 | R | N | DEVICE_ID[7] | TI device ID. Contains 0x40. |
| | 6 | 1 | R | Ν | DEVICE_ID[6] | |
| | 5 | 0 | R | N | DEVICE_ID[5] | |
| | 4 | 0 | R | N | DEVICE_ID[4] | |
| | 3 | 0 | R | N | DEVICE_ID[3] | |
| | 2 | 0 | R | N | DEVICE_ID[2] | |
| | 1 | 0 | R | N | DEVICE_ID[1] | |
| | 0 | 0 | R | N | DEVICE_ID[0] | |
| 0xF3 | | 0x00 | | | Channel Control | |
| | 7 | 0 | R | N | CHAN_VERSION[3] | TI digital channel version ID. Contains 0x00. |
| | 6 | 0 | R | N | CHAN_VERSION[2] | |
| | 5 | 0 | R | N | CHAN_VERSION[1] | |
| | 4 | 0 | R | N | CHAN_VERSION[0] | |
| | 3 | 0 | R | N | SHARE_VERSION[3] | TI digital share version ID. Contains 0x00. |
| | 2 | 0 | R | N | SHARE_VERSION[2] | |
| | 1 | 0 | R | N | SHARE_VERSION[1] | |
| | 0 | 0 | R | N | SHARE_VERSION[0] | |
| 0xFC | | 0x00 | | | General | |
| | 7 | 0 | RW | N | EN_CH7 | Select channel 7 |
| | 6 | 0 | RW | N | EN_CH6 | Select channel 6 |
| | 5 | 0 | RW | N | EN_CH5 | Select channel 5 |
| | 4 | 0 | RW | N | EN_CH4 | |
| | 3 | 0 | RW | N | EN_CH3 | Select channel 3 |
| | 2 | 0 | RW | N | EN_CH2 | Select channel 2 |
| | 0 | 0 | | N N | EN_CHI | Select channel 1 |
| | 0 | 0×00 | RVV | IN | EN_CHU | |
| UXFD | 7 | 0,00 | R\// | N | | RESERVED |
| | 6 | 0 | | N | | |
| | 5 | 0 | R\// | N | | |
| | <u>з</u> | 0 | RW/ | N | RESERVED | RESERVED |
| | + 2 | 0 | R\// | N | RESERVED | RESERVED |
| | 2 | 0 | RW/ | N | RESERVED | RESERVED |
| | 1 | 0 | R\// | N | RESERVED | RESERVED |
| | 0 | 0 | RW/ | N | | |
| | U | U | RVV | IN | RESERVED | RESERVED |

Table 2. Global Register Map (continued)



Register Maps (continued)

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|---------------|-----|------------------|------|--------|-----------------|---|
| 0xFE | | 0x03 | | | Vendor ID | |
| | 7 | 0 | R | N | VENDOR_ID[7] | TI vendor ID. Contains 0x03. |
| | 6 | 0 | R | N | VENDOR_ID[6] | |
| | 5 | 0 | R | N | VENDOR_ID[5] | |
| | 4 | 0 | R | N | VENDOR_ID[4] | |
| | 3 | 0 | R | N | VENDOR_ID[3] | |
| | 2 | 0 | R | N | VENDOR_ID[2] | |
| | 1 | 1 | R | N | VENDOR_ID[1] | |
| | 0 | 1 | R | N | VENDOR_ID[0] | |
| 0xFF | | 0x10 | | | Channel Control | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | EN_SHARE_Q1 | Select shared registers for Quad 1 (Channels 4-7). |
| | 4 | 1 | RW | N | EN_SHARE_Q0 | Select shared registers for Quad 0 (Channels 0-3). |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | WRITE_ALL_CH | Allows customer to write to all channels as if they are the same, but only allows to read back from the channel specified in 0xFC and 0xFD. |
| | | | | | | Note: EN_CH_SMB must be = 1 or else this function is invalid. |
| | 0 | 0 | RW | N | EN_CH_SMB | 1: Enables SMBus access to the channels specified in register 0xFC. |
| | | | | | | 0: The shared registers are selected, see 0xFF[5:4]. |

Table 2. Global Register Map (continued)

NSTRUMENTS

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7.6.3 Shared Registers

| Table | 3 | Shared | Reo | lister | Man |
|-------|----|--------|-------|--------|-----|
| Table | υ. | Unarca | TYC U | 13101 | map |

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|---------------|-----|------------------|------|--------|----------------------------|--|
| 0x00 | | 0x0C | | | General | |
| | 7 | 0 | R | N | I ² C ADDR[3] | I ² C strap observation. The device 7-bit slave address is 0x18 + |
| | 6 | 0 | R | N | I ² C_ADDR[2] | I ² C_ADDR[3:0]. |
| | 5 | 0 | R | N | I ² C_ADDR[1] | |
| | 4 | 0 | R | N | I ² C_ADDR[0] | |
| | 3 | 0 | R | N | RESERVED | RESERVED |
| | 2 | 0 | R | N | RESERVED | RESERVED |
| | 1 | 0 | R | N | RESERVED | RESERVED |
| | 0 | 0 | R | N | RESERVED | RESERVED |
| 0x01 | | 0x00 | | | Version Revision | |
| | 7 | 0 | R | N | RESERVED | RESERVED |
| | 6 | 0 | R | N | RESERVED | RESERVED |
| | 5 | 0 | R | N | RESERVED | RESERVED |
| | 4 | 0 | R | N | RESERVED | RESERVED |
| | 3 | 0 | R | N | RESERVED | RESERVED |
| | 2 | 0 | R | N | RESERVED | RESERVED |
| | 1 | 0 | R | N | RESERVED | RESERVED |
| | 0 | 0 | R | N | RESERVED | RESERVED |
| 0x02 | | 0x00 | | | Channel Control | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x03 | | 0x00 | | | Channel Control | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x04 | | 0x01 | | | General | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RWSC | N | RST_I ² C_REGS | 1: Reset shared registers, bit is self-clearing. |
| | | - | | | | 0: Normal operation |
| | 5 | 0 | RWSC | N | RST_I ² C_MAS | 1: Self-clearing reset for I ² C master. |
| | | | | | | 0: Normal operation |
| | 4 | 0 | RW | N | FRC_EEPRM_RD | 1: Override EN_SMB and input chain status to force EEPROM Configuration. |
| | | 0 | | NI | | |
| | 3 | 0 | KW | N N | | |
| | 2 | 0 | KW | N | REGS_CLOCK_EN | |
| | | U . | KW | N | IC_MAS_CLK_EN | |
| | 0 | 1 | RW | N | I ² CSLV_CLK_EN | RESERVED |

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Table 3. Shared Register Map (continued)

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|---------------|----------|------------------|---------|----------|-------------------------|--|
| 0x05 | | 0x00 | | | General | · · |
| | 7 | 0 | RW | N | DISAB_EEPRM_CFG | 1: Disable Master Mode EEPROM Configuration (If not started, not effective midway or after configuration). |
| | | | 514 | | | 0: Normal operation |
| | 6 | 0 | RW | N | CRC_EN | RESERVED |
| | 5 | 0 | RW | N | _CONTROL | RESERVED |
| | 4 | 0 | R | N | EEPROM_READING _DONE | Sets 1 when EEPROM reading is done. |
| | 3 | 0 | R | N | RESERVED | RESERVED |
| | 2 | 0 | R | Y | CAL_CLK_INV_DIS | 1: Disable the inversion of CAL_CLK_OUT. |
| | | | | | | 0: Normal operation, CAL_CLK_OUT is inverted with respect to CAL_CLK_IN. |
| | 1 | 0 | R | Ν | RESERVED | RESERVED |
| | 0 | 0 | R | N | TEST0_AS_CAL _CLK | RESERVED |
| 0x06 | | 0x00 | | | General | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x07 | | 0x00 | | | General | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | R | N | CAL_CLK_DET | Indicates that CAL_CLK has been detected. Indicates that CAL_CLK has not been detected. |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | MR_CAL_CLK_DET | 1: Disable CAL_CLK detect. |
| | | | | | _DIS | 0: Enable CAL_CLK detect. |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | Y | DIS_CAL_CLK_OUT | 1: Disable CAL_CLK_OUT, output is high-Z. |
| | | | | | | 0: Enable CAL_CLK_OUT. |
| 0x08 | | 0x00 | | | General | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | Ν | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| 0.00 | 0 | 0 | RW | N | RESERVED | |
| 0x09 | - | 0000 | | NI | General | |
| | (| U | ĸ | IN N | RESERVED | |
| | <u>р</u> | 0 | ĸ | IN NI | | |
| | C A | 0 | r. | IN NI | | |
| | 4 | 0 | r. P | IN N | | |
| L | 3 | U | N. | IN | RESERVED | |

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Addr

24

2

1

0

0

0

1

RW

RW

RW

Ν

Ν

Ν

I²C_FLTR_DEPTH[2]

I²C_FLTR_DEPTH[1]

I²C_FLTR_DEPTH[0]

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| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|---------------|-----|------------------|------|--------|--------------------------------|--|
| | 2 | 0 | R | N | RESERVED | RESERVED |
| | 1 | 0 | R | N | RESERVED | RESERVED |
| | 0 | 0 | R | N | RESERVED | RESERVED |
| 0x0A | | 0x00 | | | General | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | Ν | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | Ν | RESERVED | RESERVED |
| | 2 | 0 | RW | Ν | RESERVED | RESERVED |
| | 1 | 0 | R | Ν | RESERVED | RESERVED |
| | 0 | 0 | R | Ν | RESERVED | RESERVED |
| 0x0B | | 0x00 | | | | |
| | 7 | 0 | R | Ν | EECFG_CMPLT | 11: Not valid |
| | | | | | | 10: EEPROM load completed successfully. |
| | 6 | 0 | R | Ν | EECFG_FAIL | 01: EEPROM load failed after 64 attempts. |
| | | | | | | 00: EEPROM load in progress. |
| | 5 | 0 | R | N | EECFG_ATMPT[5] | Indicates number of attempts made to load EEPROM image. |
| | 4 | 0 | R | N | EECFG_ATMPT[4] | |
| | 3 | 0 | R | N | EECFG_ATMPT[3] | |
| | 2 | 0 | R | Ν | EECFG_ATMPT[2] | |
| | 1 | 0 | R | N | EECFG_ATMPT[1] | |
| | 0 | 0 | R | N | EECFG_ATMPT[0] | |
| 0x0C | | 0x91 | | | | |
| | 7 | 1 | RW | Ν | I ² C_FAST | 1: EEPROM load uses Fast I ² C Mode (400 kHz). |
| | | | | | | 0: EEPROM load uses Standard I ² C Mode (100 kHz). |
| | 6 | 0 | RW | N | I ² C_SDA_HOLD[2] | Internal SDA Hold Time |
| | 5 | 0 | RW | N | I ² C_SDA_HOLD[1] | This field configures the amount of internal hold time provided for the SDA input relative to the SDC input. Units are 100 ns. |
| | 4 | 1 | RW | N | I ² C_SDA_HOLD[0] | |
| | 3 | 0 | RW | N | I ² C_FLTR_DEPTH[3] | I ² C Glitch Filter Depth |

This field configures the maximum width of glitch pulses on the SDC and SDA inputs that will be rejected. Units are 100 ns.

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Table 3. Shared Register Map (continued)





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7.6.4 Channel Registers

Table 4. Channel Register Map

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|---------------|-----|------------------|-------|--------|----------------|---|
| 0x00 | | 0x00 | | | General | |
| | 7 | 0 | RW | N | CLK_CORE_DISAB | 1: Disables 10 M core clock. This is the main clock domain for all the state machines. 0: Normal operation |
| | 6 | 0 | RW | N | CLK_REGS_EN | Force enable the clock to the registers. Normally, the register clock is enabled automatically on a needed basis. Normal operation |
| | 5 | 0 | RW | Ν | RESERVED | RESERVED |
| | 4 | 0 | RW | N | CLK_REF_DISAB | 1: Disables the 25 MHz CAL_CLK domain. 0: Normal operation |
| | 3 | 0 | RW | Ν | RST_CORE | 1: Reset the 10 M core clock domain. This is the main clock domain for all the state machines. 0: Normal operation |
| | 2 | 0 | RWSC | N | RST_REGS | 1: Reset channel registers to power-up defaults. 0: Normal operation |
| | 1 | 0 | RW | Ν | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RST_CAL_CLK | 1: Resets the 25 MHz reference clock domain. 0: Normal operation |
| 0x01 | | 0x00 | | | SIG_DET | |
| | 7 | 0 | R | N | SIGDET | Signal detect status. 1: Signal detected at RX inputs. 0: No signal detected at RX inputs. |
| | 6 | 0 | R | Ν | RESERVED | RESERVED |
| | 5 | 0 | R | N | RESERVED | RESERVED |
| | 4 | 0 | R | N | RESERVED | RESERVED |
| | 3 | 0 | R | N | RESERVED | RESERVED |
| | 2 | 0 | R | N | RESERVED | RESERVED |
| | 1 | 0 | R | N | RESERVED | RESERVED |
| | 0 | 0 | R | N | RESERVED | RESERVED |
| 0x02 | | 0x00 | | | | |
| | 7 | 0 | R | N | RESERVED | RESERVED |
| | 6 | 0 | R | N | RESERVED | RESERVED |
| | 5 | 0 | R | N | RESERVED | RESERVED |
| | 4 | 0 | R | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | IN NI | RESERVED | |
| 0×02 | 0 | 0.200 | R V V | IN | | |
| 0.03 | 7 | 1 | RW/ | v | EO BW[1] | EQ stage one buffer current (strength) control Impacts EQ bandwidth |
| | 6 | 0 | RW | Y | EQ_BW[0] | 2 b11 yields highest bandwidth, 2 b00 yields lowest bandwidth. Refer to the Programming Guide for more information. |
| | 5 | 0 | RW | Y | EQ_BST2[2] | EQ boost stage 2 controls. Directly goes to analog. No override bit is |
| | 4 | 0 | RW | Y | EQ_BST2[1] | needed. Refer to the Programming Guide for more information. |
| | 3 | 0 | RW | Y | EQ_BST2[0] | |
| | 2 | 0 | RW | Y | EQ_BST1[2] | EQ boost stage 1 controls. Directly goes to analog. No override bit is |
| | 1 | 0 | RW | Y | EQ_BST1[1] | needed. Refer to the Programming Guide for more information. |
| | 0 | 0 | RW | Y | EQ_BST1[0] | |
| 0x04 | | 0x90 | | | | |
| | 7 | 1 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | EQ_PD_SD | 1: Power down signal detect |
| | | | | | | 0: Normal operation |

Table 4. Channel Register Map (continued)

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|---------------|-----|------------------|------|--------|------------------|---|
| | 5 | 0 | RW | Y | EQ HIGH GAIN | 1: Enable EQ high gain |
| | | | | | | 0: Enable EQ low gain |
| | 4 | 1 | RW | Y | EQ_EN_DC_OFF | RESERVED |
| | 3 | 0 | RW | Y | EQ_PD_EQ | 1: Power down EQ |
| | | | | | | 0: Enable EQ |
| | 2 | 0 | RW | Ν | RESERVED | RESERVED |
| | 1 | 0 | RW | Y | BG_SEL_IPP100[2] | CTLE bias programming. BG_SEL_IPP100[1:0] is in Reg_0x0F[5:4]. |
| | 0 | 0 | RW | Y | EQ_EN_BYPASS | 1: Enable EQ boost stage 1 (BST1) bypass |
| | | | | | | 0: Normal operation, signal travels through boost stage 1 (BST1) |
| 0x05 | | 0x04 | | | SIG_DET_CONFIG | |
| | 7 | 0 | RW | Y | EQ_SD_PRESET | 1: Force signal detect result to 1 |
| | | | | | | 0: Normal operation |
| | | | | | | This bit should not be set if 0x05[6] is also set. |
| | 6 | 0 | RW | Y | EQ_SD_RESET | 1: Force signal detect result to 0 |
| | | | | | | 0: Normal operation |
| | | | | | | This bit should not be set if 0x05[7] is also set. |
| | 5 | 0 | RW | Y | EQ_REFA_SEL[1] | Signal detect assert thresholds. Refer to the Programming Guide for more |
| | 4 | 0 | RW | Y | EQ_REFA_SEL[0] | information. |
| | 3 | 0 | RW | Y | EQ_REFD_SEL[1] | Signal detect de-assert thresholds. Refer to the Programming Guide for |
| | 2 | 1 | RW | Y | EQ_REFD_SEL[0] | more information. |
| | 1 | 0 | RW | Ν | RESERVED | RESERVED |
| | 0 | 0 | RW | Ν | RESERVED | RESERVED |
| 0x06 | | 0xC0 | | | | |
| | 7 | 1 | RW | Y | DRV_SEL_VOD[1] | Driver VOD adjust (DC gain), applicable to both linear and FIR limiting |
| | 6 | 1 | RW | Y | DRV_SEL_VOD[0] | mode. Refer to the Programming Guide for more information. |
| | 5 | 0 | RW | Y | DRV_EQ_PD_OV | 1: Driver and equalizer power down manually with Reg_0x06[3] and Reg_0x04[3], respectively. |
| | | | | | | 0: Driver and equalizer are powered down or up by default when LOS=1/0. |
| | 4 | 0 | RW | Y | DRV_SEL_MUTE | Driver mute override: |
| | | | | | _01 | 1: Use register 0x06[1] for mute control. |
| | | | | | | 0: Normal operation. Mute is automatically controlled by signal detect. |
| | 3 | 0 | RW | Y | DRV_PD | 1: Power down the driver. |
| | | | | | | 0: Normal operation, driver power on or off is controlled by signal detect. |
| | 2 | 0 | RW | Y | DRV_PD_CM_LOOP | 1: Disable the driver's common mode loop control circuit. |
| | | | | | | 0: Normal operation, common mode loop enabled. |
| | 1 | 0 | RW | Y | DRV_SEL_MUTE | 1: Mute driver if override bit is enabled. |
| | | | | | | 0: Normal operation |
| | 0 | 0 | RW | Y | DRV_SEL_FIR | Linear versus Limiting Mode select. Refer to the Programming Guide for more information. 1: Enable Limiting FIR mode. |
| | | | | | | 0: Enable Linear mode (disable limiting FIR). |
| 0x07 | | 0x20 | | | | |
| | 7 | 0 | RW | Ν | RESERVED | RESERVED |
| | 6 | 0 | RW | Ν | RESERVED | RESERVED |
| | 5 | 1 | RW | Ν | RESERVED | RESERVED |
| | 4 | 0 | RW | Ν | RESERVED | RESERVED |
| | 3 | 0 | RW | Ν | RESERVED | RESERVED |
| | 2 | 0 | RW | Ν | RESERVED | RESERVED |
| | 1 | 0 | RW | Ν | RESERVED | RESERVED |
| | 0 | 0 | RW | Ν | RESERVED | RESERVED |
| 0x08 | | 0x54 | | | | |
| | 7 | 0 | RW | Y | RESERVED | RESERVED |

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Table 4. Channel Register Map (continued)

| Addr | Bit | Default | Mode | FERROM | Field | Description |
|--------|-----|---------|-------|--------|----------------|---|
| [IIEX] | 6 | 1 | RW | V | RESERVED | RESERVED |
| | 5 | 0 | RW/ | v | REGERVED | RESERVED |
| | 4 | 1 | RW | Y | RESERVED | RESERVED |
| | 3 | 0 | RW/ | v | BC SEL IPTAT25 | 1: Increases the current to the CTLE by 5% |
| | 5 | 0 | 1 | | | 0. Default |
| | 2 | 1 | D\// | N | | |
| | 1 | 0 | RW/ | N | RESERVED | RESERVED |
| | 0 | 0 | DW/ | N | | |
| 0×00 | 0 | 0×00 | IN VV | IN | RESERVED | |
| 0,03 | 7 | 0,000 | DW/ | N | | |
| | 6 | 0 | | N | | |
| | 5 | 0 | DW/ | N | | |
| | 1 | 0 | | N | | |
| | - 4 | 0 | | N | | |
| | 2 | 0 | | N | | |
| | | 0 | | N | | |
| | 0 | 0 | | N | | |
| 0×04 | 0 | 0×30 | | IN | RESERVED | |
| UNUA | 7 | 0,50 | DW/ | N | | |
| | 6 | 0 | RW/ | V | RESERVED | RESERVED |
| | 5 | 1 | | I V | | Signal datect threshold controls: |
| | 1 | 1 | | v v | | 11: Normal operation |
| | 4 | 1 | 17.00 | 1 | SD_GAIN | 10: Signal detect assert or de-assert thresholds reduced. |
| | | | | | | 00: Signal detect assert or de-assert thresholds reduced. |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | Ν | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x0B | | 0x1A | | | | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | Y | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 1 | RW | Y | FIR_MAIN[4] | FIR Limiting mode main-cursor control. Refer to the Programming Guide for |
| | 3 | 1 | RW | Y | FIR_MAIN[3] | more information. |
| | 2 | 0 | RW | Y | FIR_MAIN[2] | |
| | 1 | 1 | RW | Y | FIR_MAIN[1] | |
| | 0 | 0 | RW | Y | FIR_MAIN[0] | |
| 0x0C | | 0x40 | | | | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 1 | RW | Y | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | Y | FIR_PST[3] | FIR Limiting mode post-cursor control. There is no sign bit for the post- |
| | 2 | 0 | RW | Y | FIR_PST[2] | the Programming Guide for more information. |
| | 1 | 0 | RW | Y | FIR_PST[1] | |
| | 0 | 0 | RW | Y | FIR_PST[0] | |
| 0x0D | | 0x40 | | | | |
| | 7 | 0 | RW | Ν | RESERVED | RESERVED |
| | 6 | 1 | RW | Y | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | Ν | RESERVED | RESERVED |

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Addr [HEX]

Bit

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| Product Folder | Links: | DS280BR820 |
|----------------|--------|------------|

| | Table 4. Channel Register Map (continued) | | | | | | | | |
|------------------|---|--------|------------|--|--|--|--|--|--|
| Default [HEX] | Mode | EEPROM | Field | Description | | | | | |
| 0 | RW | Y | FIR_PRE[3] | FIR Limiting mode pre-cursor control. There | | | | | |
| 0 | RW | Y | FIR PRE[2] | cursor. The pre-cursor always provides a hig | | | | | |

| | 3 | 0 | RW | Y | FIR_PRE[3] | FIR Limiting mode pre-cursor control. There is no sign bit for the pre- |
|------|---|------|----|---|-------------------------|--|
| | 2 | 0 | RW | Y | FIR_PRE[2] | cursor. The pre-cursor always provides a high-pass filter effect. Refer to the Programming Guide for more information. |
| | 1 | 0 | RW | Y | FIR_PRE[1] | |
| | 0 | 0 | RW | Y | FIR_PRE[0] | |
| 0x0E | | 0x00 | | | | |
| | 7 | 0 | RW | Ν | RESERVED | RESERVED |
| | 6 | 0 | RW | Ν | RESERVED | RESERVED |
| | 5 | 0 | RW | Ν | RESERVED | RESERVED |
| | 4 | 0 | RW | Ν | RESERVED | RESERVED |
| | 3 | 0 | RW | Ν | RESERVED | RESERVED |
| | 2 | 0 | RW | Ν | RESERVED | RESERVED |
| | 1 | 0 | RW | Ν | RESERVED | RESERVED |
| | 0 | 0 | RW | Ν | RESERVED | RESERVED |
| 0x0F | | 0x00 | | | | |
| | 7 | 0 | RW | Ν | RESERVED | RESERVED |
| | 6 | 0 | RW | Ν | RESERVED | RESERVED |
| | 5 | 0 | RW | Y | BG_SEL_IPP100[1] | CTLE bias programming. BG_SEL_IPP100[2] is in Reg_0x04[1]. |
| | 4 | 0 | RW | Y | BG_SEL_IPP100[0] | 000: 0% additional current (Default) 001: 5% additional current 010: 10% additional current 011: 15% additional current 100: 20% additional current 101: 25% additional current 110: 30% additional current 111: 35% additional current |
| | 3 | 0 | RW | Y | BG_SEL_IPH200 _v1[1] | Program pre-driver bias current: 00: 0% additional current (Default) |
| | 2 | 0 | RW | Y | BG_SEL_IPH200 _v1[0] | 01: 12.5% additional current 10: 25% additional current 11: 37.5% additional current |
| | 1 | 0 | RW | Y | BG_SEL_IPH200 _v0[1] | Program driver bias current: 00: 0% additional current (Default) |
| | 0 | 0 | RW | Y | BG_SEL_IPH200 _v0[0] | 11: 12.5% additional current 10: 25% additional current 11: 37.5% additional current |





8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The DS280BR820 is a high-speed linear repeater which extends the reach of differential channels impaired by loss from transmission media like PCBs and cables. It can be deployed in a variety of different systems. The following sections outline typical applications and their associated design considerations.

8.2 Typical Applications

The DS280BR820 is typically used in three main application scenarios:

- 1. Backplane and mid-plane reach extension
- 2. Front-port eye opening for copper and optical applications



Figure 6. Typical Application Diagram

NOTE

TI recommends to AC couple the DS280BR820's high-speed outputs. In some cases, ASIC or FPGA SerDes receivers support DC coupling, and it may be desirable to DC couple the DS280BR820 output with the ASIC/FPGA RX input to reduce the PCB area which would normally be consumed by AC coupling capacitors. To DC couple the DS280BR820 output with an ASIC RX input, the ASIC RX must support DC coupling and it must support an input common mode voltage of 1.05 V. To determine if the ASIC RX supports DC coupling, here are some items to consider based on Figure 7:

- 1. The ASIC RX must be AC coupled on-chip.
- 2. The ASIC RX should not force a DC bias on the RX pins.
- 3. System designers should ensure that when the PCB powers on, the power supply rails are appropriately sequenced to prevent the DS280BR820's output common mode voltage from forward-biasing the ESD structure of the ASIC or violating the absolute maximum input voltage specifications of the ASIC.

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Typical Applications (continued)



Figure 7. Considerations for DC Coupling to ASIC RX

8.2.1 Backplane and Mid-Plane Reach Extension

The DS280BR820 has strong equalization capabilities that allow it to equalize insertion loss and extend the reach of backplane channels by 17-22 dB beyond the normal capabilities of the ASICs operating over the channel. The DS280BR820 is designed to apply gain in a linear fashion. In most cases, the DS280BR820 should be placed with the higher loss channel segment at the input and the lower loss channel segment at the output; however, since the DS280BR820 operates in a linear fashion, it can also be used in applications where the lower loss channel segment is at the input and the higher loss channel segment is at the output. Refer to Figure 8.







Typical Applications (continued)





Typical Applications (continued)

8.2.1.1 Design Requirements

For backplane and mid-plane reach extension application use the guidelines in the table below.

| DESIGN PARAMETER | REQUIREMENT |
|---|--|
| AC Coupling Capacitors | Generally not required. 220-nF AC coupling capacitors are included in the DS280BR820 package on the RX side. |
| Input Channel Insertion Loss | \geq 10 dB at 14 GHz as a rough guideline. For best performance, the input channel insertion loss should be greater than or equal to the equalizer boost setting used in the DS280BR820. |
| Output Channel Insertion Loss | Depends on downstream ASIC or FPGA SerDes capabilities. Should be ≥ 5 dB at 14 GHz as a rough guideline. |
| Total (Input + Output) Channel Insertion Loss | Depends on downstream ASIC or FPGA SerDes capabilities. The DS280BR820 can extend the reach between two ASICs by 17 to 22 dB beyond the ASICs' normal capabilities. |
| Link Partner TX Launch Amplitude | 800 mV _{PP} to 1200 mV _{PP} differential. |
| Link Partner TX FIR Filter | Depends on the channel loss. |

8.2.1.2 Detailed Design Procedure

The design procedure for backplane and mid-plane applications is as follows:

- 1. Determine the total number of channels on the board which require a DS280BR820 for signal conditioning. This will dictate the total number of DS280BR820 devices required. It is generally recommended that channels with similar total insertion loss on the board be grouped together in the same DS280BR820 device. This will simplify the device settings, as similar loss channels generally utilize similar settings.
- 2. Determine the maximum current draw required for all DS280BR820 devices. This may impact the selection of the regulator for the 2.5-V supply rail. To calculate the maximum current draw, multiply the maximum power supply current by the total number of DS280BR820 devices.
- 3. Determine the SMBus address scheme needed to uniquely address each DS280BR820 device on the board, depending on the total number of devices identified in step 1. Each DS280BR820 can be strapped with one of 16 unique SMBus addresses. If there are more DS280BR820 devices on the board than the number of unique SMBus addresses which can be assigned, then use an I²C expander like the TCA/PCA family of I²C/SMBus switches and multiplexers to split the SMBus into multiple busses.
- 4. Determine if the device will be configured from EEPROM (SMBus master mode) or from the system SMBus (SMBus slave mode).
 - a. If SMBus master mode will be used, provisions should be made for an EEPROM on the board with 8-bit SMBus address 0xA0.
 - b. If SMBus slave mode will be used for all device configurations, an EEPROM is not needed.
- 5. Make provisions in the schematic and layout for standard decoupling capacitors between the device VDD supply and GND. Refer to *Power Supply Recommendations* for more information.
- 6. If there is a need to potentially upgrade to a pin-compatible TI Retimer device, then make provisions in the schematic and layout for a 25-MHz (±100 ppm) single-ended CMOS clock. Each DS280BR820 buffers the clock on the CAL_CLK_IN pin and presents the buffered clock on the CAL_CLK_OUT pin. This allows multiple (up to 20) DS280BR820 calibration clocks to be daisy chained to avoid the need for multiple oscillators on the board. If the oscillator used on the board has a 2.5 V CMOS output, then no AC coupling capacitor or resistor ladder is required at the input to CAL_CLK_IN. No AC coupling or resistor ladder is needed between one DS280BR820 CAL_CLK_OUT output and the next DS280BR820's CAL_CLK_IN input. The final DS280BR820's CAL_CLK_OUT output can be left floating. A 25 MHz clock is not required for the DS280BR820, but it is good practice to provision for it in case there is a future plan to upgrade to a pin-compatible TI Retimer device.
- 7. If there is a need to potentially upgrade to a pin-compatible TI Retimer device, then connect the INT_N pin to an FPGA or CPU for interrupt monitoring. Note that multiple INT_N outputs can be connected together. The common INT_N net should be pulled high to 2.5 V or 3.3 V. The INT_N pin on the DS280BR820 does not perform the interrupt functionality that the equivalent pin on the pin-compatible Retimer device does; however, it is good practice to provision for this in case there is a future plan to upgrade to a pin-compatible TI Retimer device.



8.2.2 Front-Port Applications

The DS280BR820 has strong equalization capabilities that allow it to equalize insertion loss and extend the reach of front-port channels by 17 dB beyond the normal capabilities of the ASIC while support CAUI-4 and CR4 electrical requirements. The DS280BR820 is designed to apply gain in a linear fashion in order to support longer distances between the switch ASIC and the front-port module. A single DS280BR820 can be used to support all eight *egress* channels or all eight *ingress* channels for two 100 GbE ports. Figure 10 illustrates this configuration.



Figure 10. Typical Front-Port Application Diagram

Standard front-port modules have AC coupling capacitors included inside the module. The DS280BR820, therefore, is ideal for front-port Egress signal conditioning applications since it includes AC coupling capacitors on the input (RX) side and does not include AC coupling capacitors on the output (TX) side.



Figure 11. DS280BR820 Recommended for Front-port Egress

The optimum solution for front-port Ingress signal conditioning applications depends on whether the ASIC RX supports DC coupling and whether it can support an input common mode voltage of 1.05 V. For further guidance on determining if the ASIC RX supports DC coupling, refer to Figure 7. If the ASIC RX supports DC coupling and can tolerate an input common mode voltage of 1.05 V or less, then the DS280BR820 is the optimum solution for front-port Ingress signal conditioning. If the ASIC RX does not support DC coupling or cannot tolerate an input common mode voltage of 1.05 V, then the pin-compatible DS280BR810 may be the optimum solution.

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Figure 12. DS280BR820 Recommended for Front-port Ingress



Figure 13. DS280BR820 or DS280BR810 Recommended for Front-port Ingress



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FXAS

8.2.2.1 Design Requirements

This section lists some critical areas for high speed printed circuit board design consideration and study.

| DESIGN PARAMETER | REQUIREMENT |
|---------------------------------|---|
| AC Coupling Capacitors | Generally not required. 220 nF AC coupling capacitors are included in the DS280BR820 package on the RX side. |
| Input Channel Insertion Loss | \geq 10 dB at 14 GHz as a <i>rough</i> guideline. For best performance, the input channel insertion loss should be greater than or equal to the equalizer boost setting used in the Repeater. |
| Output Channel Insertion Loss | For best performance in <i>egress</i> applications, place the Repeater close to the front-port cage. For best performance in <i>ingress</i> applications, place the Repeater with \geq 5 dB loss at 14 GHz between the output and the downstream ASIC. |
| Switch ASIC TX Launch Amplitude | 600 mVppd to 1000 mVppd |

8.2.2.2 Detailed Design Procedure

The design procedure for front-port applications is as follows:

- Determine the total number of channels on the board which require a DS280BR820 for signal conditioning. This will dictate the total number of DS280BR820 devices required for the board. It is generally recommended that channels belonging to the same QSFP port be grouped together in the same DS280BR820 device. This will simplify the device settings, as similar loss channels generally utilize similar settings.
- 2. Determine the maximum current draw required for all DS280BR820 devices. This may impact the selection of the regulator for the 2.5 V supply rail. To calculate the maximum current draw, multiply the maximum power supply current by the total number of DS280BR820 devices.
- 3. Determine the SMBus address scheme needed to uniquely address each DS280BR820 device on the board, depending on the total number of devices identified in step 1. Each DS280BR820 can be strapped with one of 16 unique SMBus addresses. If there are more DS280BR820 devices on the board than the number of unique SMBus addresses which can be assigned, then use an I²C expander like the TCA/PCA family of I²C/SMBus switches and multiplexers to split the SMBus into multiple busses.
- 4. Determine if the device will be configured from EEPROM (SMBus master mode) or from the system I²C bus (SMBus slave mode).
 - 1. If SMBus master mode will be used, provisions should be made for an EEPROM on the board with 8-bit SMBus address 0xA0.
 - 2. If SMBus slave mode will be used for all device configurations, an EEPROM is not needed.
- 5. Make provisions in the schematic and layout for standard decoupling capacitors between the device VDD supply and GND. Refer to *Power Supply Recommendations* for more information.



8.2.3 Application Curves

8.2.3.1 Pattern Generator Characteristics

All of the example application results in the sections which follow were tested using a pattern generator with the following characteristics.







Table 5. Pattern Generator Characteristics

| | 25.78125 Gbps | 10.3125 Gbps |
|--|-----------------------|------------------------|
| Differential peak-to-peak voltage (VOD) | ~800 mVppd | ~800 mVppd |
| Channel loss between Pattern Generator and Scope | 2 dB @ 12.9 GHz | 1 dB @ 5.2 GHz |
| Total Jitter @ 1E-15 | 8.0 ps _{P-P} | 13.4 рs _{P-P} |
| Differential Eye Height @ 1E-15 | 448 mV _{P-P} | 596 mV _{P-P} |

8.2.3.2 Equalizing Moderate Pre-Channel Loss

This example application result demonstrates the DS280BR820 equalizing for pre-channel insertion loss introduced by an FR4 channel.



Figure 18. 5 in input Channel and Minimal Output Channel Test Setup



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Table 6. Settings and Measurements for CAUI-4 and nPPI with 5 in Input Channel and Minimal Output Channel

| | 25.78125 Gbps (CAUI-4) | 10.3125 Gbps (nPPI) |
|---------------------------------|---------------------------------|---------------------------------|
| Transmission Line 1 | 5 in 5 mil FR4 + 8 in SMA cable | 5 in 5 mil FR4 + 8 in SMA cable |
| DS280BR820 Rx Channel Loss | 14 dB @ 12.9 GHz | 6 dB @ 5.2 GHz |
| DS280BR820 Tx Channel Loss | 4.5 dB @ 12.9 GHz | 2 dB @ 5.2 GHz |
| EQ BST1 | 3 | 3 |
| EQ BST2 | 0 | 0 |
| EQ BW | 3 | 3 |
| VOD | 3 | 2 |
| EQ DC Gain Mode | Low | Low |
| Total Jitter @ 1E-15 | 11.9 ps _{P-P} | 13.0 ps _{P-P} |
| Differential Eye Height @ 1E-15 | 338 mV _{P-P} | 544 mV _{P-P} |
| Mask violations | 0 | 0 |

8.2.3.3 Equalizing High Pre-Channel Loss

This example application result demonstrates the DS280BR820 equalizing for pre-channel insertion loss introduced by an FR4 channel.



Figure 21. 10 in Input Channel and Minimal Output Channel Test Setup



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Table 7. Settings and Measurements for CAUI-4 and nPPI with 10 in Input Channel and Minimal Output Channel

| | 25.78125 Gbps (CAUI-4) | 10.3125 Gbps (nPPI) |
|---------------------------------|----------------------------------|----------------------------------|
| Transmission Line 1 | 10 in 5 mil FR4 + 8 in SMA cable | 10 in 5 mil FR4 + 8 in SMA cable |
| DS280BR820 Rx Channel Loss | 22 dB @ 12.9 GHz | 10 dB @ 5.2 GHz |
| DS280BR820 Tx Channel Loss | 4.5 dB @ 12.9 GHz | 2 dB @ 5.2 GHz |
| EQ BST1 | 6 | 6 |
| EQ BST2 | 1 | 1 |
| EQ BW | 3 | 3 |
| VOD | 3 | 2 |
| EQ DC Gain Mode | Low | Low |
| Total Jitter @ 1E-15 | 11.3 рs _{P-P} | 13.5 рs _{P-P} |
| Differential Eye Height @ 1E-15 | 210 mV _{P-P} | 532 mV _{P-P} |
| Mask violations | 0 | 0 |

8.2.3.4 Equalizing High Pre-Channel Loss and Moderate Post-Channel Loss

This example application result demonstrates the DS280BR820 equalizing for pre-channel and post-channel insertion loss introduced by FR4 channels.



Figure 24. 10 in Input Channel and 5 in Output Channel Test Setup



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Table 8. Settings and Measurements for CAUI-4 and nPPI with 10 in Input Channel and 5 in Output Channel

| | 25.78125 Gbps (CAUI-4) | 25.78125 Gbps (CAUI-4) | 10.3125 Gbps (nPPI) |
|---------------------------------|----------------------------------|----------------------------------|----------------------------------|
| Transmission Line 1 | 10 in 5 mil FR4 + 8 in SMA cable | 10 in 5 mil FR4 + 8 in SMA cable | 10 in 5 mil FR4 + 8 in SMA cable |
| Transmission Line 2 | 5 in 5 mil FR4 + 8 in SMA cable | 5 in 5 mil FR4 + 8 in SMA cable | 5 in 5 mil FR4 + 8 in SMA cable |
| DS280BR820 Rx Channel Loss | 22 dB @ 12.9 GHz | 22 dB @ 12.9 GHz | 10 dB @ 5.2 GHz |
| DS280BR820 Tx Channel Loss | 14.5 dB @ 12.9 GHz | 14.5 dB @ 12.9 GHz | 6 dB @ 5.2 GHz |
| EQ BST1 | 7 | 7 | 7 |
| EQ BST2 | 7 | 7 | 7 |
| EQ BW | 3 | 3 | 3 |
| VOD | 3 | 3 | 2 |
| EQ DC Gain Mode | Low | Low | Low |
| Tx Mode | Linear | FIR Limiting | Linear |
| Tx Main-Cursor | N/A | 16 | N/A |
| Tx Pre-Cursor | N/A | 5 | N/A |
| Tx Post-Cursor | N/A | 10 | N/A |
| Total Jitter @ 1E-15 | 14.8 ps _{P-P} | 14.8 ps _{P-P} | 17.0 ps _{P-P} |
| Differential Eye Height @ 1E-15 | 67 mV _{P-P} | 118 mV _{P-P} | 407 mV _{P-P} |
| Mask violations | N/A | 0 | 0 |



8.2.3.5 Output in FIR Limiting Mode with 16T Pattern

This example application result demonstrates the DS280BR820's output in FIR limiting mode.



Table 9. Example FIR Settings

| Figure 29 | Figure 30 |
|---------------------------------|---------------------------------|
| (Pre, Main, Post) = (0, 12, 0) | (Pre, Main, Post) = (0, 12, 0) |
| (Pre, Main, Post) = (0, 16, 15) | (Pre, Main, Post) = (11, 12, 0) |

8.3 Initialization Set Up

The DS280BR820 does not require any particular start-up or initialization sequence. The device defaults to a medium boost value for each channel. It is recommend that the channels be appropriately configured before data traffic is transmitted to the DS280BR820 to avoid issues with the link partner ASIC's adaption. Example configuration settings can be found in the DS280BR820 Programming Guide.

9 **Power Supply Recommendations**

Follow these general guidelines when designing the power supply:

- 1. The power supply should be designed to provide the recommended operating conditions outlined in *Specifications* in terms of DC voltage, AC noise, and start-up ramp time.
- 2. The maximum current draw for the DS280BR820 is provided in *Specifications*. This figure can be used to calculate the maximum current the supply must provide. Typical mission-mode current draw can be inferred from the typical power consumption in *Specifications*.
- 3. The DS280BR820 *does not* require any special power supply filtering, such as ferrite beads, provided the recommended operating conditions are met. Only standard supply decoupling is required. Typical supply decoupling consists of a 0.1-μF capacitor per power pin, and single 1.0-μF and 10-μF bulk capacitors.



10 Layout

10.1 Layout Guidelines

The following guidelines should be followed when designing the layout:

- 1. Decoupling capacitors should be placed as close to the VDD pins as possible. Placing them directly underneath the device is one option if the board design permits.
- 2. High-speed differential signals should be tightly coupled, skew matched, and impedance controlled.
- 3. Vias should be avoided when possible on the high-speed differential signals. When vias must be used, care should be taken to minimize the via stub, either by transitioning through most or all layers, or by back drilling.
- 4. GND relief can be used beneath the high-speed differential signal pads to improve signal integrity by counteracting the pad capacitance.
- 5. GND vias should be placed directly beneath the device connecting the GND plane attached to the device to the GND planes on other layers. This has the added benefit of improving thermal conductivity from the device to the board.
- BGA landing pads for a 0.8 mm pitch flip-chip BGA are typically 0.4 mm in diameter (exposed). The actual size of the copper pad will depend on whether solder-mask-defined (SMD) or non-solder-mask-defined solder land pads are used. For more information, refer to TI's Surface Mount Technology (SMT) References website.

10.2 Layout Examples

10.2.1 Stripline Example

The following example layout demonstrates how all signals can be escaped from the BGA array using stripline routing on a generic 8+ layer stackup. This example layout assumes the following:

- Trace width: 0.15 mm (6 mil)
- Trace edge-to-edge spacing: 0.16 mm (6.4 mil)
- VIA finished hole size (diameter): 0.254 mm (10 mil)
- VIA-to-VIA spacing: 1.0 mm (39 mil), to enhance PCB manufacturability
- No VIA-in-pad used

Note that many other escape routing options exist using different trace width and spacing combinations. The optimum trace width and spacing will depend on the PCB material, PCB routing density, and other factors. Microstrip escape routing is also possible and may be preferable in some application scenarios such as front-port applications.





Layout Examples (continued)



10.2.2 Microstrip Example

The following example layout demonstrates how all signals can be escaped from the BGA array using microstrip routing on a generic 8+ layer stackup. This example layout assumes the following:

- Normal trace width: 0.27 mm (10.5 mil)
- Neck-down trace width: 0.18 mm (7 mil)
- Trace edge-to-edge spacing: 0.51 mm (20 mil)
- VIA finished hole size (diameter): 0.203 mm (8 mil)
- VIA-to-VIA spacing: 0.8 mm (31.5 mil)
- No VIA-in-pad used

Note that many other escape routing options exist using different trace width and spacing combinations. The optimum trace width and spacing will depend on the PCB material, PCB routing density, and other factors. Stripline escape routing is also possible and may be preferable in some application scenarios such as backplane applications.



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Layout Examples (continued)





11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation see the following:

- Texas Instruments, DS280BR810EVM User's Guide
- Texas Instruments, DS280BR810 Programming Guide
- Texas Instruments, Understanding EEPROM Programming for 25G and 28G Repeaters and Retimers Application Report
- Texas Instruments, Selection Guide for TI 25G and 28G Retimers and Repeaters Application Report

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Trademarks

All trademarks are the property of their respective owners.

11.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.



10-Dec-2020

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|---------|
| DS280BR820ZBLR | ACTIVE | NFBGA | ZBL | 135 | 1000 | RoHS & Green | SNAGCU | Level-3-260C-168 HR | -40 to 85 | DS280BR8A | Samples |
| DS280BR820ZBLT | ACTIVE | NFBGA | ZBL | 135 | 250 | RoHS & Green | SNAGCU | Level-3-260C-168 HR | -40 to 85 | DS280BR8A | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020



Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| * | All dimensions are nominal | | | | | | | | | | | | |
|---|----------------------------|-----------------|--------------------|------|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| | Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| Ī | DS280BR820ZBLR | NFBGA | ZBL | 135 | 1000 | 330.0 | 24.4 | 8.4 | 13.4 | 1.9 | 12.0 | 24.0 | Q2 |
| I | DS280BR820ZBLT | NFBGA | ZBL | 135 | 250 | 178.0 | 24.4 | 8.4 | 13.4 | 1.9 | 12.0 | 24.0 | Q2 |

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PACKAGE MATERIALS INFORMATION

9-Aug-2022



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| DS280BR820ZBLR | NFBGA | ZBL | 135 | 1000 | 367.0 | 367.0 | 45.0 |
| DS280BR820ZBLT | NFBGA | ZBL | 135 | 250 | 213.0 | 191.0 | 55.0 |

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PACKAGE OUTLINE

NFBGA - 1.43 mm max height

PLASTIC BALL GRID ARRAY



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.



ZBL0135A

EXAMPLE BOARD LAYOUT

NFBGA - 1.43 mm max height

PLASTIC BALL GRID ARRAY



3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.

For information, see Texas Instruments literature number SPRAA99 (www.ti.com/lit/spraa99).



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EXAMPLE STENCIL DESIGN

NFBGA - 1.43 mm max height

PLASTIC BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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